



K120

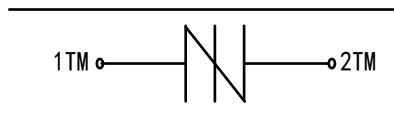
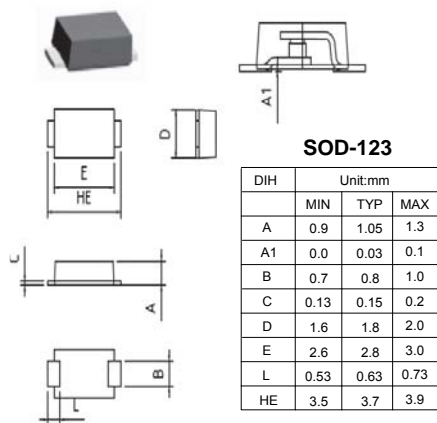
硅高压双向触发二极管
峰值工作电流 1A

特征 Features

- 高压钠灯触发器 High pressure Sodium Vapor Lighting
- 高压调整器 High Voltage Regulators
- 脉冲发生器 Pulse Generators
- 代替可控硅 Used to Trigger Gates of SCR's and Triacs
- 无铅器件 These are pb free Devices*
- LDE灯保护 LED lamp protection

机械数据 Mechanical Data

- 端子: 镀锡轴向引线 Terminals: Plated axial leads
- 安装位置: 任意 Mounting Position: Any



极限值和温度特性 TA = 25°C 除非另有规定。

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Rating	符号 Symbols	K120	单位 Unit
最大可重复峰值反向电压 Maximum repetitive peak reverse voltage (Sine Wave, 50to60Hz, T _J =-40to125°C)	V _{DRM} V _{RIRM}	±90	V
开态均方根电流 On-state RMS current(T _L =80°C, Lead Length=3/8", All Conduction Angles)	I _{T(RMS)}	±1.0	A
最大浪涌电流 Peak Non Repetitive Surge Current (60Hz One Cycle Sine-wave, T _J =125°C)	I _{TSM}	±20	A
工作温度 Operating Junction Temperature Range	T _J	-40 to +125	°C
储存温度 Storage Temperature Range	T _{stg}	-40 to +125	°C
典型热阻 Thermal Resistance, Junction-to-lead (LEAD LENGTH=3/8")	R _{θJA}	15	°C/W
焊接温度 Lead Solder Temperature (Lead length ≥ 1/16" from Case, 10s Max)	T _L	275	°C



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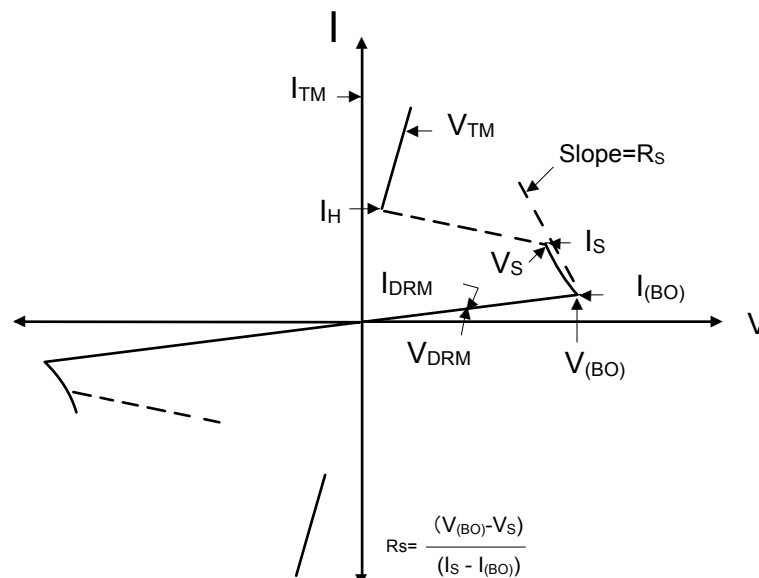
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电特性 TC = 25°C 除非另有规定。

ELECTRICAL CHARACTERISTICS (TC = 25°C unless otherwise noted;Electricals apply in both directions)

电特性 Characteristic	符号 Symbols	K120	单位 Unit
转折电压 Breakover Voltage, $I_{BO}=200\mu A$	Min	110	V
	Max	130	
反向漏电流 Repetitive peak Off-State Current (50to60Hz Sine Wave)	I_{DRM}	5	μA
转折电流 Breakover Current	I_{BO}	10	μA
通态峰值电压 Peak On_State Voltage ($I_{TM}=1A$ Peak,Pulse Width $\leq 300\mu s$,Duty Cycle $\leq 2\%$)	V_{TM}	Max 1.5	V
动态维持电流 Dynamic Holding Current (Sine Wave,60Hz, $R_L=100\Omega$)	Typ	30	mA
	Max	60	
切换电阻 Switching Resistance (Sine Wave,50to60Hz)	R_S	0.1	K Ω
电流上升率 Critical rate_of_rise of on_state Current, Critical Damped Eaveform Circuit ($I_{PK}=130\Omega$,Pulse Width=10 μsec)	di/dt	120	A/ μS

硅高压双向触发二极管的特性曲线 Voltage Characteristic Characteristic of SIDAC (Bidirectional Device)

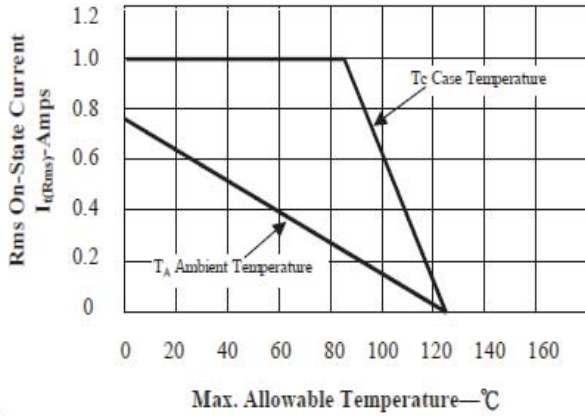




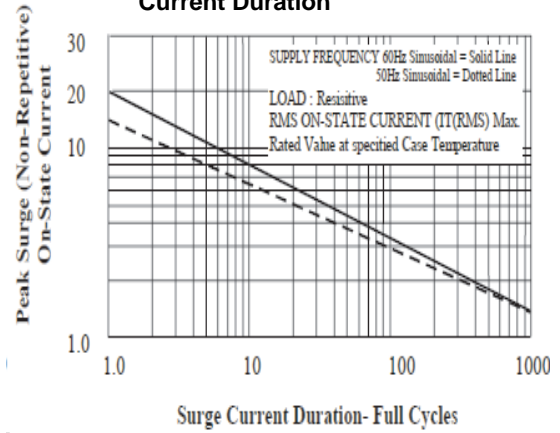
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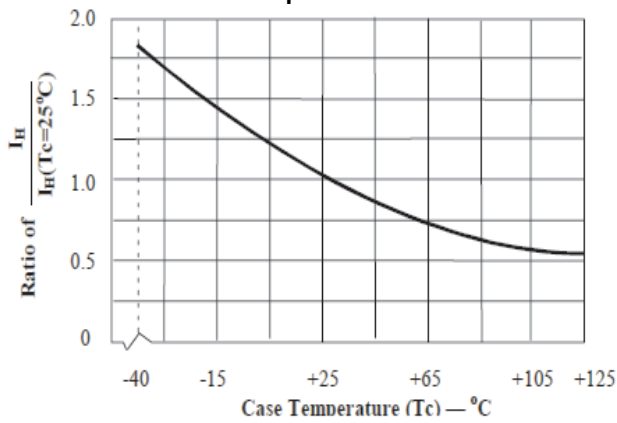
Maximum Allowable Case Temperature vs On State Current (And Ambient)



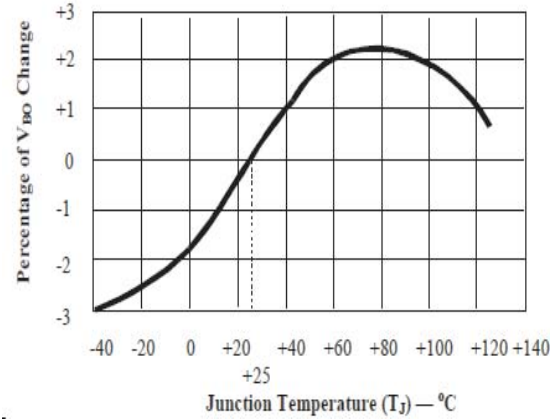
Peak Surge Current vs Surge Current Duration



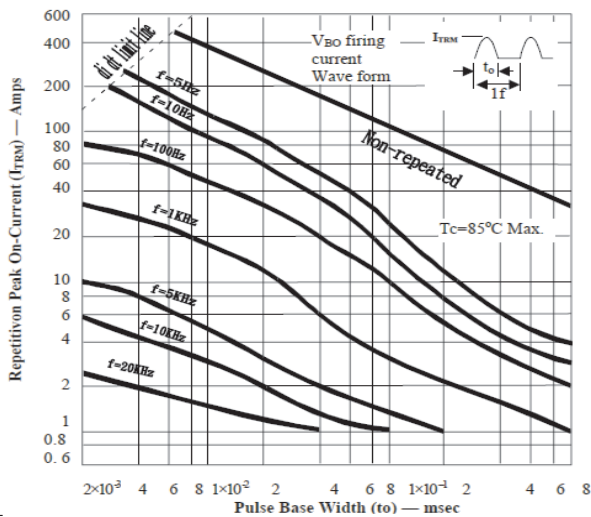
Normalized DC Holding Current vs Case Temperature



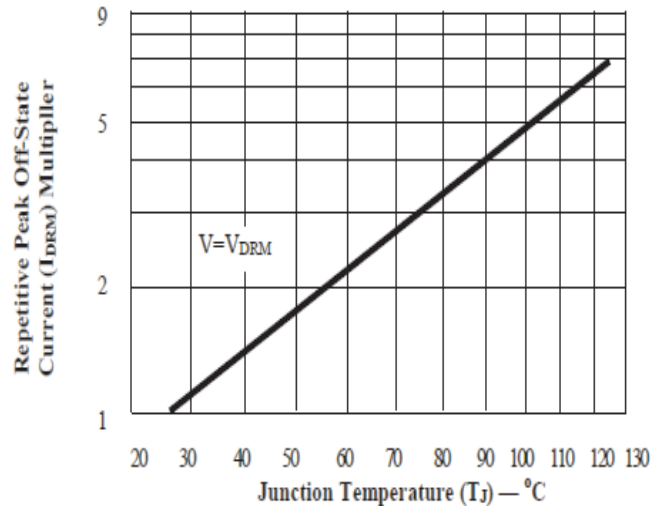
Normalized V_BO Change vs Junction Temperature



High Frequency Current Capacity



Normalized Repetitive Peak Off-State Current vs Junction Temperature



单击下面可查看定价，库存，交付和生命周期等信息

[>>ZG\(中鑫半导体\)](#)